NSN 5962-00-985-2181

Memory Microcircuit - Page 1 of 1



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Body Length:

Between 0.660 inches and 0.785 inches

Body Width:

Between 0.220 inches and 0.280 inches

Body Height:

Between 0.140 inches and 0.180 inches

Maximum Power Dissipation Rating:

450.0 milliwatts

Operating Tempurature Range:

+0.0/+70.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Monolithic and hermetically sealed and programmable and programmed and positive outputs

Inclosure Material:

Ceramic and glass

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Current-mode logic

Input Circuit Pattern:

8 input

Case Outline Source And Designator:

T0-116 joint electron device engineering council

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

20.0 volts power source

Time Rating Per Chacteristic:

100.00 nanoseconds propagation delay time, low to high level output

Memory Device Type:

Rom

Terminal Type And Quantity:

14 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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